International Islamic University Chittagong

Department of Computer Science and Engineering

B.Sc. in CSE, Final Examination, Spring 2022

Course Code: EEE-1221

Course Title: Electronics

Time: 2 hours 30 minutes

Full Marks: 50

(i) The figures in the right-hand margin indicate full marks

(ii) Course Outcomes and Bloom's Levels are mentioned in additional Columns

_	_	Post A			_
		Part A [Answer all the questions from the followings]			
1.	a)	Write down the difference between JFET and BJT. Describe its construction and working principle of (N-Channel JFET).	CO4	U	7
		 i) When gate-source voltage (V_{GS}) is applied and drain-source voltage is zero i.e. V_{DS}= 0V. 			
		 ii) When drain-source voltage (V_{DS}) is applied at constant gate-source voltage (V_{GS}) 			
		· Or,			
		What is MOSFET? What are the different types of MOSFET? With a neat diagram, explain the working principle of an n-channel enhancement type MOSFET.			
1.	b)	A JFET has the following parameters: I _{DSS} = 32 mA; V _{GS(off)} = -8V; V _{GS} = -4.5 V. Find out the value of drain current.	CO4	A	3
2.	a)	What is a multivibrator? Mention different types of multivibrators with proper waveshapes. With neat diagrams, explain the working of an astable multivibrator. Or,	CO4	U	5
		What is an oscillator? What are the essentials of an oscillator? With the help of a neat diagram, describe the circuit operation of a Hartley oscillator.			
2.	b)	Fig. 2(b) shows the transistor switching circuit. Given that $R_B = 2.7 \text{ k}\Omega$, $V_{BB} = 2V$, $V_{BE} = 0.7V$ and $V_{knee} = 0.7V$.	CO4	A	5
		 i) Calculate the minimum value of β for saturation. ii) If V_{BB} is changed to 1V and transistor has minimum β = 50, will the transistor be saturated. 			
		+ V _{CC} = 10V			
		$R_{C} = 1 \text{ L}\Omega$			
		$V_{BB} = \frac{R_B = 2.7 \text{ k}\Omega}{V_{BB}}$			-
		Fig. 2(b)			
		·			Τ

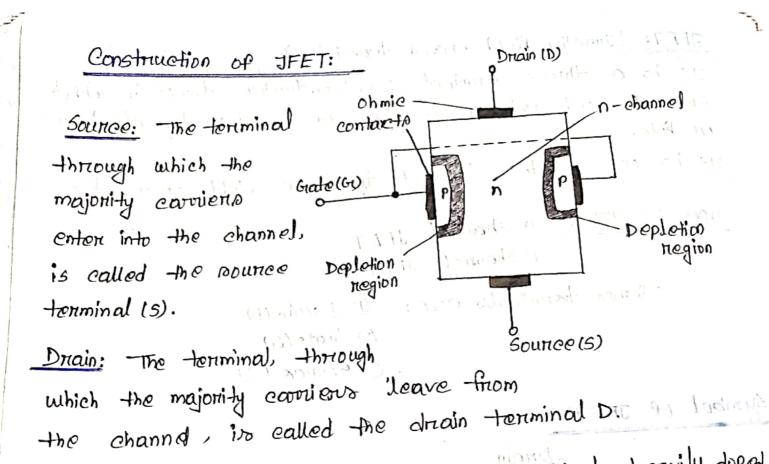
1		Part B [Answer the questions from the followings]			
	a)	Show that when the gain of summing amplifier is unity, the output voltage is the algebraic sum of the input voltages with proper circuit diagram. Or, Show that the output is the integral of the input with an inversion and scale multiplier of 1/RC.			
3.	b)	Determine the output voltage from the circuit shown in Fig. 3(b) for each of the following input combinations:	CO5	٨	
		$V_1(V)$ $V_2(V)$ $V_3(V)$ + 10 0 +10 0 +10 +10 +10 +10			
		$V_1 \circ V_2 \circ V_3 \circ V_3 \circ V_4 \circ V_5 \circ V_6 \circ V_7 \circ V_8 $			
4.	(a)	Fig. 3(b) What is negative feedback? Show that the input impedance of an amplifier	CO5	•	_
4.	+	increases due to negative feed. Calculate the operating frequency and feedback fraction of the following	COS	U A	4
		oscillator where the mutual inductance between two coils is $20\mu H$. R_1 R_2 R_3 R_4 R_4 R_5 R_5 R_6 R_5 R_6			
5	. a	What is negative feedback?. Show that the input impedance of an amplifier increases due to negative feed.	CO5	U	5
5	. b	Write short on : i) Precision Rectifiers ii) Comparators Or,	CO5	U	5
\		What is an operational amplifier? Draw the circuit diagram of non-inverting OP-AMP with indicating different terminals. Also show the voltage gain of a non-inverting amplifier is $1 + \frac{R_f}{R_i}$.			

and gain of regative seedback.

EEE (Previous) Spring-22

110) Difference between IFET and BIT:

JFET	BJT
D Voltage control device.	O Cumment control device.
3 Unipolar device	@ Bipolar device
3 Input Impedence high.	5) Input Impedence low.
4) Lens noisy	9 Mone noisy.
3 Hone temporatione Stable	5 Leno-temporation stable



Grate: There are two intornally connected heavily doped negiona to creede tuo P-N junctiona more negions over called the gote terminal Gr. Channel: The negion between the source and drain, vaandwiched between the two glasses gators in called the 776 Barmalo - Cr

channel.

When gate rounce voltage (vus) is applied and drain-Sounce voltage (vDs) vo zeno, i.e., VDs = OV.

- Juhan Vors = ov, two depletion layer and channel one formed normally.
- ⇒ when Vas inenease negativity i.e, ov>Vas>Vas(+++)

 depletion layern are also incheased and channel will

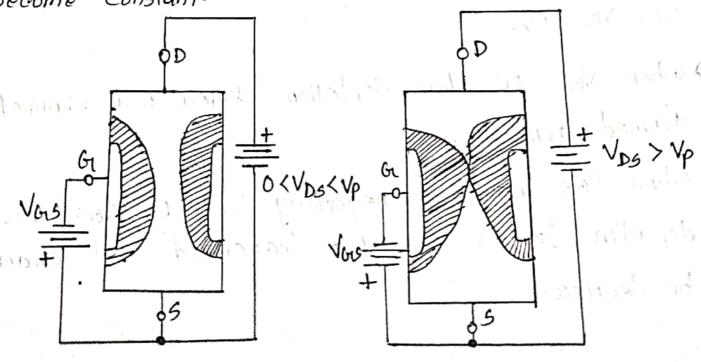
 be decrease.

when Vus = Vus (off) depletion layor will be touch each other and channel will totally removed.

50, no current can flow through the channel.

Constant gate - source Voltage (VDS) vo applied at

- Now trevence bias at the drain end is larger than sounce and end and so the depletion layer is widen at the drain end than bounce end.
- when Vos increases i.e out vostle depletion layer at drain end is gradually increased and drain current also increased.
- Hon Vos = Vp the channel in effectively closed at drain end and it does not allow further increase of drain current. Too the drain current will become constant.



J(a) OR

MOSFET: It is a semiconductor device which is widely used for sountching and amplifying electronic signals in the electronics devices.

Typero of MOSFET: There are two typor of HOSFET.

- 1. Deplition HOSFET
- 2. Enhancement MosfET

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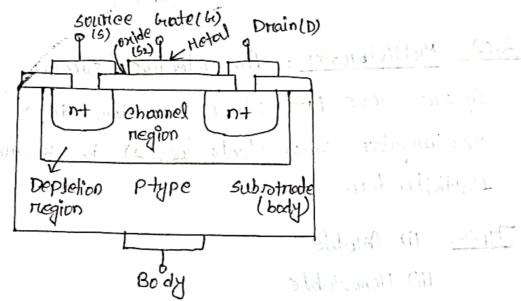
> n-channel

=> n-channel

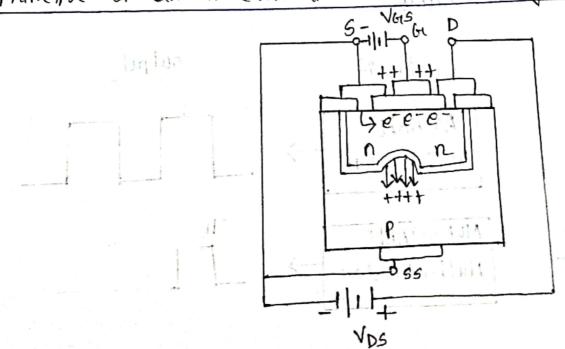
> P-channel

> p-channel

Diagram (n-channel MOSFET):



Working Principle of an n-channel enhancement type MOSFET



The device body that is formed due to p-type and the terminal source are connected to a common ground. A positive polarity of the voltage is applied to the terminal gate. Because of this positivism, it corresponds to an effect of the capacitor. Hence in the p substrate, the minority carriers that are free electrons get attracted and move towards the terminal gate.

Due to this a layer that is because of uncovered ions is formed bellow the layer of dielectric where the combinations of the holes with electrons occur. As the positive voltage applied gradually increases and crosses the minimum threshold the electrons which are minority carriers would be able to overcome the recombination with the holes and they form the channel between the two p type material.

Further application of the positive voltage value at the drain leads to the flow of current through the transistor. The concentrations of the electrons are dependent on the potential applied. These concentrations of the electrons are responsible for the formation of the channel and the application of the voltage at gate enhances the flow of the current. Hence it is termed as N- channel MOSFET of enhancement type.

drain cunnent, ID

$$= 32 \left[1 - \frac{\sqrt{4.5}}{\sqrt{8.5}(0FF)}\right]$$

$$= 32 \left[1 - \frac{-84.5}{-8}\right]$$

$$= 34$$

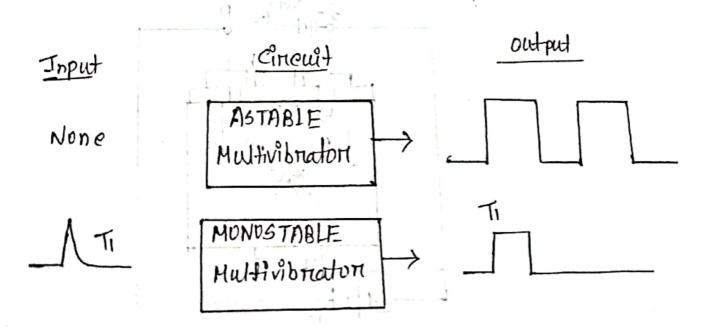
2100 Multivibration: An electric cincuit. that general square wave (for other non-sinusoidal so such as nectangular, saw-tools waves) is known as Multivibration.

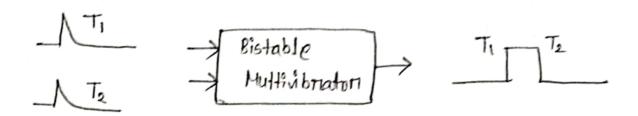
rece sections, training

Types: 1i) Astable

lii) Monostable

1 Forth 39 (iii) Biestable dos brands or an 12 objected [





⇒ Explain Astable multivibration (ਸਤਾਂਤਰੀ)

2(a) or

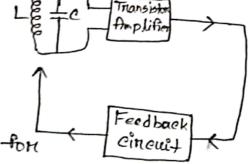
Oscillation: A device for generating oscillatory electric currents on voltages by non-mechanical means.

Essential of oscillaton: It exprential components are

in parallel with capaciton (c). Frequercy depends upon the

Values of includtance of the coil and capacitance of the Capaciton.

die powen from the battery and changes it into a e powen for



Supplying to the tank cinewit. The oscillations occurring in the transistor tank cinewit are applied to the input of the transistor amplifien. Because of the amplifying properties of the transistor, we get increased output of these oscillations.

Part of collector energy to the tank cincuit in connect phase to aid the oscillations i.e. it provides positive-feedback

Sinusoidal Oscillators

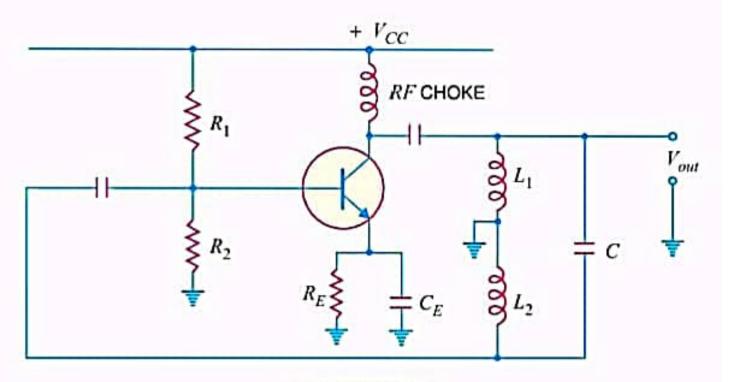


Fig. 14.13

Circuit operation. When the circuit is turned on, the capacitor is charged. When this capacitor is fully charged, it discharges through coils L_1 and L_2 setting up oscillations of frequency determined by *exp. (i). The output voltage of the amplifier appears across L_1 and feedback voltage across L_2 . The voltage across L_2 is 180° out of phase with the voltage developed across L_1 (V_{out}) as shown in Fig. 14.14. It is easy to see that voltage fedback (i.e., voltage across L_2) to the transistor provides positive feedback. A phase shift of 180° is produced by the transistor and a further phase shift of 180° is produced by $L_1 - L_2$ voltage divider. In this way, feedback is properly phased to produce continuous undamped oscillations.

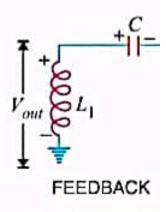


Fig. 14.14

Summing Amplifien: A summing amplifien in an invented of-amp that ean accept two on mone inputs. The output voltage of a roumming amplifien is proportional to the negative of the algebraic sum of the input vostagers.

(Question!) > show that the output voltage is proportional to the algebraic roum of the input Vollages. }

when all the three inputs one applied, output voltage is, Vout = - JIRF

$$= -R_{f} (J_{1} + J_{2} + J_{9})$$

$$= -R_{f} (\frac{V_{1}}{R_{1}} + \frac{V_{2}}{R_{2}} + \frac{V_{3}}{R_{3}})$$

$$= -R_{f} (J_{1} + J_{2} + J_{9})$$

Vout = -Rf
$$\left(\frac{\sqrt{1}}{R_1} + \frac{\sqrt{2}}{R_2} + \frac{\sqrt{3}}{R_3}\right)$$

If, $R_1 = R_2 - R_g = R$ then we have, Void = $-\frac{Rf}{R}(V_1+V_2+V_3)$

IF, Rf = R19 = R2 = R3 = R then output voltage is. Vout = - (V1+V2+V3)

Thur, when the gain of summing amplifien is unity the output voltage is the algebraic sum of the inpu Vollagers, .. Vout = $-\frac{KF}{R} \left[V_1 + V_2 + V_3 + - \cdots \right]$

3(a) OR	Date:///
op-Amp Integration: An integration	is a cineuit that pentermo
- integration of the input roignal th	ēriē, =feedbackcomponent-in-oz
- Capaciton involvad - of a - revistor	$\stackrel{i}{\Rightarrow} \stackrel{R}{\longrightarrow} \stackrel{A}{\longrightarrow} \stackrel{i_3}{\longrightarrow} \stackrel{C}{\longrightarrow}$
Vi-o i m OV C R A UP-amp	
R A UP-amp	
<u></u>	
	<u></u>
1= 10	
$i = \frac{\sqrt{1-0}}{R} = \frac{\sqrt{1}}{R} - (1)$	
Voltage across capaciton in	o Ve = 0-VoVo
le = <u>cdv</u> = -	C dV @
From O and Q Vi = - c dv	
$\frac{dV_b}{dV_b} = -\frac{1}{RE}V_i$	<u> </u>
To tegrating both soider, of e	gn @ me get,



voltage					
fillowing,	imput	60r	hingtion	<i>(</i> ه٠	
, R ₁ =	ka r		140		

Date:/...../

in	-figure	-вон е	ach or	f the following input combinations.
·	~1(V)	1/2(V)	V3 (N)	1 = 1 kg 120V
	+10	0	+10	I-oV, o-MM
	. 0	+10	+10	13=4k2 + P
	1 10	+10	+10	

Solution: Vout =
$$-\frac{Rp}{Rp}(V_1 + V_2 + V_3)$$

= $-(\frac{Rp}{R_1}V_1 + \frac{Rp}{R_2}V_2 + \frac{pp}{R_3}V_3)$
= $-(\frac{1}{1}V_1 + \frac{1}{2}V_2 + \frac{1}{4}V_3)$
Vout = $-(V_1 + 0.5V_2 + 0.25V_3)$

Determine the output

The output Voltage for the first set of input is
$$Vout = -(10 + 0.5 \times 0 + 0.25 \times 10) = -1.25 \text{ V}$$
For the 2nd set of input is
$$Vout = -(0 + 0.5 \times 10 + 0.25 \times 10) = -7.5 \text{ V}$$
For the 3nd set of input is
$$Vout = -(10 + 0.5 \times 10 + 0.25 \times 10) = -17.5 \text{ V}$$

$$Vout = -(10 + 0.5 \times 10 + 0.25 \times 10) = -17.5 \text{ V}$$

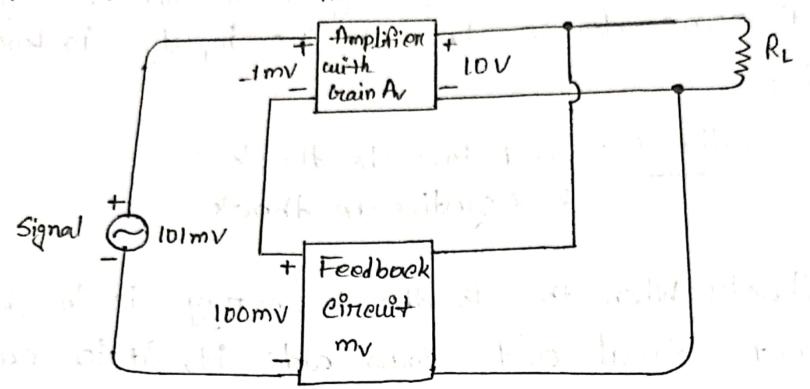


3(b)



410) Negative feedback: When the feedback energy (voltage on current) out of phase with the input signed and thus opposes it, it is called Negative feedback. Introducero 180º phase ohift Amplifien Feedback ne-twork out of phase Introduces 0 with Vin Phase phift

Principles of negative voltage foodback in Amplifican.
input impedance: 2'in = 2 in (1+ Avmv)



Grain of negative foodback amplifier.

Actual input amplifier = eg-mveo.

The output eo must be equal to the input voltage eg-mveo multiplied by gain Av of the amplifier.

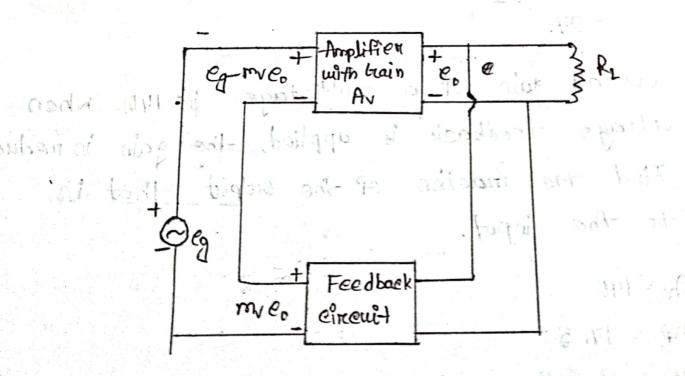
(eg-mveo) Av = eo

> Av eg - Armyeo = eo

=> coll+ Avmu) = Aveg

$$\Rightarrow \frac{C_0}{C_0} = \frac{A_V}{1 + A_V m_V}$$

- : Vo Hoge gain of with negotive facedback is, $Avp = \frac{Av}{1 + Avmv}$



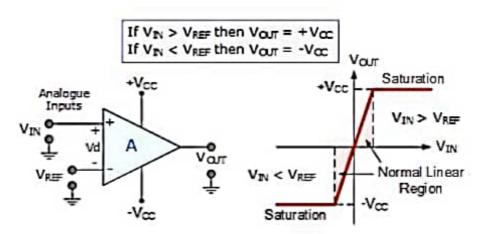
E Edback - Angelin

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Nonlinear Circuit Applications

Comparator

Op-amp Comparator Circuit:



Operation:

With reference to the op-amp comparator circuit above, lets first assume that V_{IN} is less than the DC voltage level at V_{REF} , ($V_{IN} < V_{REF}$). As the non-inverting (positive) input of the comparator is less than the inverting (negative) input, the output will be LOW and at the negative supply voltage, -Vcc resulting in a negative saturation of the output.

If we now increase the input voltage, $V_{\rm IN}$ so that its value is greater than the reference voltage $V_{\rm REF}$ on the inverting input, the output voltage rapidly switches HIGH towards the positive supply voltage, +Vcc resulting in a positive saturation of the output. If we reduce again the input voltage $V_{\rm IN}$, so that it is slightly less than the reference voltage, the op-amp's output switches back to its negative saturation voltage acting as a threshold detector.

Then we can see that the op-amp voltage comparator is a device whose output is dependent on the value of the input voltage, $V_{\rm IN}$ with respect to some DC voltage level as the output is HIGH when the voltage on the non-inverting input is greater than the voltage on the inverting input, and LOW when the non-inverting input is less than the inverting input voltage. This condition is true regardless of whether the input signal is connected to the inverting or the non-inverting input of the comparator.

We can also see that the value of the output voltage is completely dependent on the op-amps power supply voltage. In theory due to the op-amps high open-loop gain the magnitude of its output voltage could be infinite in both directions, $(\pm \infty)$. However practically, and for obvious reasons it is limited by the op-amps supply rails giving $V_{OUT} = +V_{CC}$ or $V_{OUT} = -V_{CC}$.

Precision Rectifier

Why we need Precision Rectifler:

A rectifier is a circuit that converts alternating current (AC) to Direct current (DC). An alternating current always changes its direction over time, but the direct current flows continuously in one direction. In a typical rectifier circuit, we use diodes to rectify AC to DC. But this rectification method can only be used if the input voltage to the circuit is greater than the forward voltage of the diode which is typically 0.7V. We previously explained diode-based half-wave rectifier and full-wave rectifier circuit.

To overcome this issue, the Precision Rectifler Circuit was introduced. The precision rectifier is another rectifier that converts AC to DC, but in a precision rectifier we use an op-amp to compensate for the voltage drop across the diode, that is why we are not losing the 0.6V or 0.7V voltage drop across the diode, also the circuit can be constructed to have some gain at the output of the amplifier as well.

Circuit and Operation:

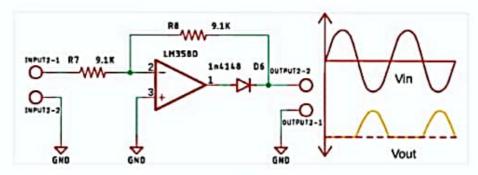


Fig. 1

The above circuit in Fig. 1 shows a basic, half-wave precision rectifier circuit with an LM358 Op-Amp and a 1n4148 diode. The above circuit also shows you the input and output waveform of the precision rectifier circuit, which is exactly equal to the input. That's because we are taking the feedback from the output of the diode and the op-amp compensates for any voltage drop across the diode. So, the diode behaves like an ideal diode.

Now in the circuit in Fig. 2, you can clearly see what happens when a positive and a negative half cycle of the input signal is applied in the input terminal of the Op-Amp. The circuit also shows the transfer characteristics of the circuit.

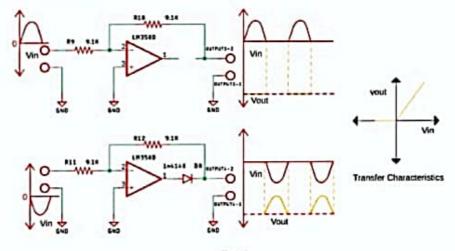
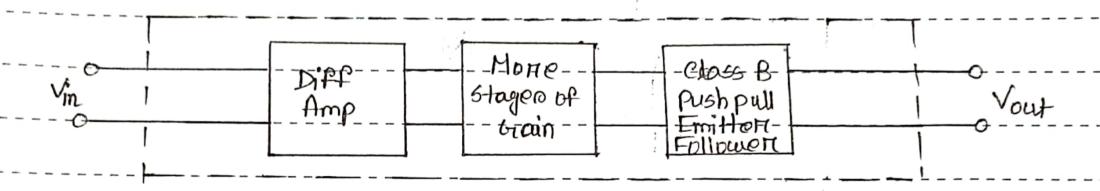


Fig. 2

51b)	OR
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Date:/...../

operation amplifier: An operation amplifier is a cineuit that can perform such mathematical operations are addition rollburgetion, integration and differentiation.



Block-diagram-of-op-amp

Date:/..../..... Non inventing amplifient A non inventing amplifier Produces an output signal that its in phase with the imput signal whencers an inventing amplifients output Vi is out of phase. Voltage Across, Ri = Vin-D Vo Hage Across, Rp = Vout - Vin Now, Curinent through Ri = Cunnent through Re > Vin Rp = Vow Ri - Vin Ri > Vin Rf + Vin Ri - Vout Ri Vin (Rf+Ri) = Vout Ri .: closed loop Voltage Gain, Act = Vout : Ael = 1+ Rf Ri-



